

900V N-Channel MOSFET

General Description

This Power MOSFET is advanced planar stripe DMOS technology.

Electrical Characteristics

$T_C = 25^\circ\text{C}$ unless otherwise noted

Notes:

1. Repetitive Rating : Pulse width limited by maximum junction temperature
2. $L = 21\text{ mH}$, $I_{AS} = 9.0\text{ A}$, $V_{DD} = 50\text{V}$, R_G

